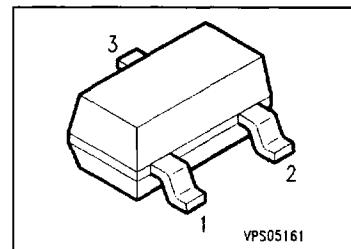


NPN Silicon AF Transistors

BCW 65
BCW 66

- For general AF applications
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BCW 67, BCW 68 (PNP)



VPS05161

Type	Marking	Ordering Code (tape and reel)	Pin Configuration			Package ¹⁾
			1	2	3	
BCW 65 A	EAs	Q62702-C1516	B			
BCW 65 B	EBs	Q62702-C1612		E		
BCW 65 C	ECs	Q62702-C1479			C	
BCW 66 F	EFs	Q62702-C1892				
BCW 66 G	EGs	Q62702-C1526				
BCW 66 H	EHs	Q62702-C1632				

¹⁾ For detailed information see chapter Package Outlines.

Maximum Ratings

Parameter	Symbol	Values		Unit	
		BCW 65	BCW 66		
Collector-emitter voltage	V_{CEO}	32	45	V	
Collector-base voltage	V_{CBO}	60	75		
Emitter-base voltage	V_{EBO}	5	5		
Collector current	I_C	800		mA	
Peak collector current	I_{CM}	1		A	
Base current	I_B	100		mA	
Peak base current	I_{BM}	200			
Total power dissipation, $T_S = 79^\circ\text{C}$	P_{tot}	330			
Junction temperature	T_J	150		°C	
Storage temperature range	T_{stg}	- 65 ... + 150			

Thermal Resistance

Junction - ambient ¹⁾	$R_{th JA}$	≤ 285	K/W
Junction - soldering point	$R_{th JS}$	≤ 215	

¹⁾ Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/6 cm² Cu.

Electrical Characteristicsat $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC characteristics

Collector-emitter breakdown voltage $I_C = 10 \text{ mA}$	$V_{(\text{BR})\text{CE}0}$				V
BCW 65		32	—	—	
BCW 66		45	—	—	
Collector-base breakdown voltage $I_C = 10 \mu\text{A}$	$V_{(\text{BR})\text{CB}0}$				
BCW 65		60	—	—	
BCW 66		75	—	—	
Emitter-base breakdown voltage, $I_E = 10 \mu\text{A}$	$V_{(\text{BR})\text{EB}0}$	5	—	—	
Collector cutoff current	I_{CBO}				
$V_{\text{CB}} = 32 \text{ V}$	BCW 65		—	20	nA
$V_{\text{CB}} = 45 \text{ V}$	BCW 66		—	20	nA
$V_{\text{CB}} = 32 \text{ V}, T_A = 150^\circ\text{C}$	BCW 65		—	20	μA
$V_{\text{CB}} = 45 \text{ V}, T_A = 150^\circ\text{C}$	BCW 66		—	20	μA
Emitter-base cutoff current, $V_{\text{EB}} = 4 \text{ V}$	I_{EBO}	—	—	20	nA
DC current gain ¹⁾	h_{FE}				—
$I_C = 100 \mu\text{A}, V_{\text{CE}} = 10 \text{ V}$					
BCW 65 A, BCW 66 F		35	—	—	
BCW 65 B, BCW 66 G		50	—	—	
BCW 65 C, BCW 66 H		80	—	—	
$I_C = 10 \text{ mA}, V_{\text{CE}} = 1 \text{ V}$					
BCW 65 A, BCW 66 F		75	—	—	
BCW 65 B, BCW 66 G		110	—	—	
BCW 65 C, BCW 66 H		180	—	—	
$I_C = 100 \text{ mA}, V_{\text{CE}} = 1 \text{ V}$					
BCW 65 A, BCW 66 F		100	160	250	
BCW 65 B, BCW 66 G		160	250	400	
BCW 65 C, BCW 66 H		250	350	630	
$I_C = 500 \text{ mA}, V_{\text{CE}} = 2 \text{ V}$					
BCW 65 A, BCW 66 F		35	—	—	
BCW 65 B, BCW 66 G		60	—	—	
BCW 65 C, BCW 66 H		100	—	—	

¹⁾ Pulse test: $t \leq 300 \mu\text{s}$, $D = 2\%$.

Electrical Characteristicsat $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

DC characteristics

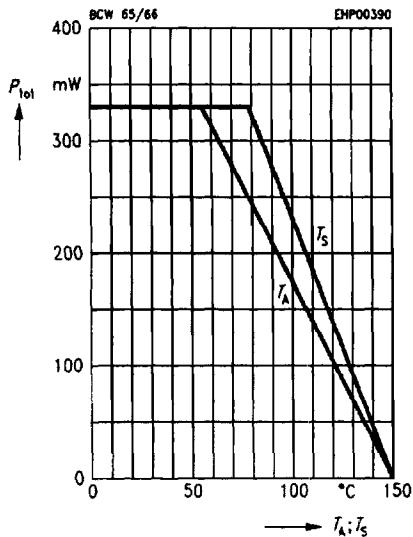
Collector-emitter saturation voltage ¹⁾ $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$	V_{CEsat}	—	—	0.3 0.7	V
Base-emitter saturation voltage ¹⁾ $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$ $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$	V_{BESat}	—	—	1.25 2	

AC characteristics

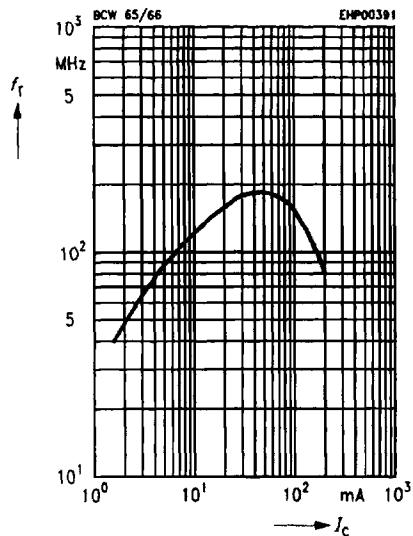
Transition frequency $I_C = 50 \text{ mA}, V_{CE} = 5 \text{ V}, f = 20 \text{ MHz}$	f_T	—	170	—	MHz
Output capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{obo}	—	6	—	pF
Input capacitance $V_{EB} = 0.5 \text{ V}, f = 1 \text{ MHz}$	C_{ibo}	—	60	—	

1) Pulse test: $t \leq 300 \mu\text{s}$, $D = 2\%$.

Total power dissipation $P_{\text{tot}} = f(T_A^*; T_S)$
 * Package mounted on epoxy

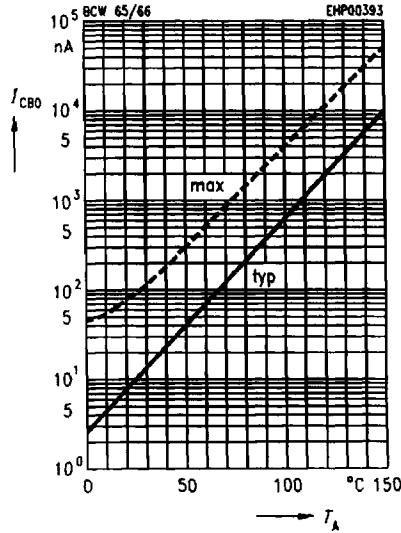
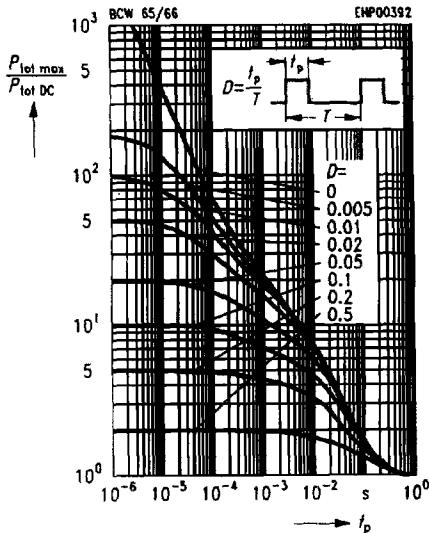


Transition frequency $f_T = f(I_C)$
 $V_{CE} = 5 \text{ V}$



Permissible pulse load $P_{\text{tot max}}/P_{\text{tot DC}} = f(t_p)$

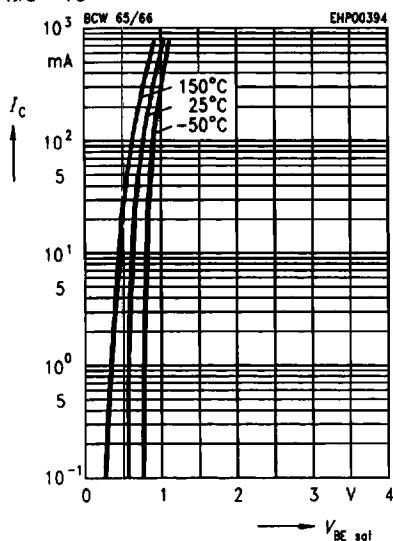
Collector cutoff current $I_{CBO} = f(T_A)$
 $V_{CB} = V_{CE\text{max}}$



Base-emitter saturation voltage

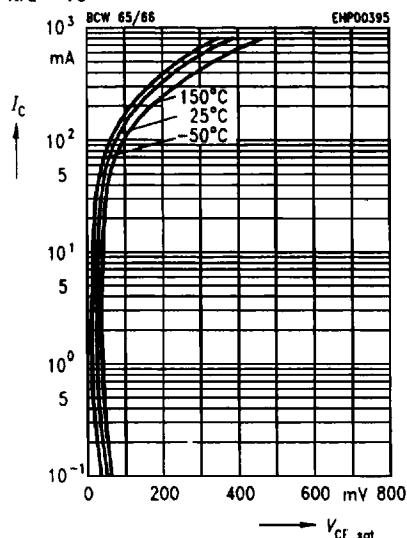
$$I_c = f(V_{BE\text{sat}})$$

$$h_{FE} = 10$$

**Collector-emitter saturation voltage**

$$I_c = f(V_{CE\text{sat}})$$

$$h_{FE} = 10$$

**DC current gain $h_{FE} = f(I_c)$**

$$V_{CE} = 1 \text{ V}$$

